

## **NCE3415Y**

## NCE P-Channel Enhancement Mode Power MOSFET

## **Description**

The NCE3415Y uses advanced trench technology to provide excellent  $R_{\text{DS}(\text{ON})}$ , low gate charge and operation with gate voltages as low as 1.8 V. This device is suitable for use as a load switch or in PWM applications .It is ESD protested.

#### **General Features**

•  $V_{DS} = -20V, I_{D} = -4A$ 

 $R_{DS(ON)}$  < 60m $\Omega$  @  $V_{GS}$ =-2.5V

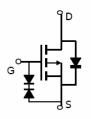
 $R_{DS(ON)}$  < 45m $\Omega$  @  $V_{GS}$ =-4.5V

ESD Rating: 2500V HBM

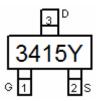
- High Power and current handing capability
- Lead free product is acquired
- Surface mount package

## **Application**

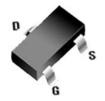
- PWM application
- Load switch



#### Schematic diagram



Marking and pin Assignment



SOT-23-3L top view

#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3415Y	NCE3415Y	SOT-23-3L	Ø180mm	8 mm	3000 units

## Absolute Maximum Ratings (TA=25℃unless otherwise noted)

	•		
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	-20	V
Gate-Source Voltage	V <sub>G</sub> S	±10	V
Drain Current-Continuous	I <sub>D</sub>	-4	Α
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	-30	Α
Maximum Power Dissipation	P <sub>D</sub>	1.4	W
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	°C

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ hetaJA}$	89.3	°C/W

## Electrical Characteristics (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	-20		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±10V,V <sub>DS</sub> =0V	-	-	±10	μA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250\mu A$	-0.35	-0.55	-0.9	V
Desir Course On Clate Besisters	_	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-4A	-	34	45	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-4A	-	44	60	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =-5V,I <sub>D</sub> =-4A	8	-	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C <sub>lss</sub>	\/ - 40\/\/ -0\/	-	950	-	PF
Output Capacitance	Coss	V <sub>DS</sub> =-10V,V <sub>GS</sub> =0V, F=1.0MHz	-	165	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0WHZ	-	120	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	12		nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =-10V, $R_L$ =2. $5\Omega$	-	10		nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =-4.5 $V$ , $R_{GEN}$ =3 $\Omega$	-	19		nS
Turn-Off Fall Time	t <sub>f</sub>		_	25		nS
Total Gate Charge	Qg	101/1 40	-	12		nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =-10V, $I_{D}$ =-4A, $V_{GS}$ =-4.5V	-	1.4	-	nC
Gate-Drain Charge	$Q_{gd}$	v <sub>GS</sub> =-4.5v	-	3.6	-	nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =-4A	-	-	-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-4	Α

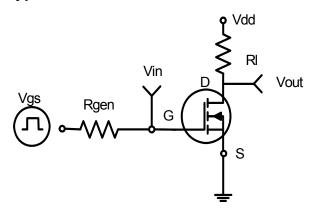
## Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤  $300\mu$ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production

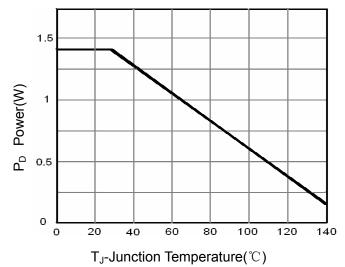


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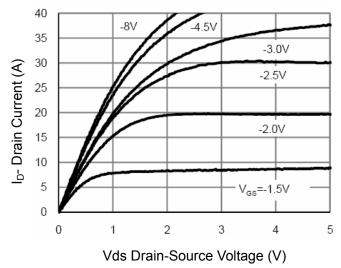
## **Typical Electrical and Thermal Characteristics**



**Figure 1:Switching Test Circuit** 



**Figure 3 Power Dissipation** 



**Figure 5 Output Characteristics** 

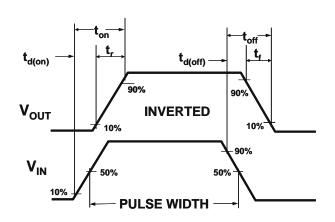
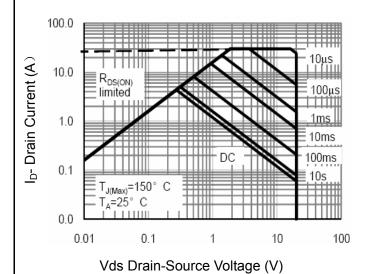


Figure 2:Switching Waveforms



**Figure 4 Safe Operation Area** 

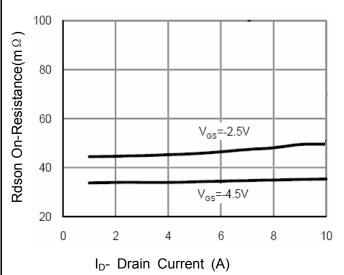
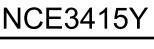
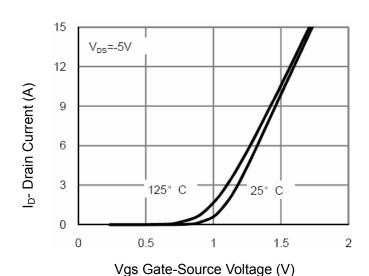


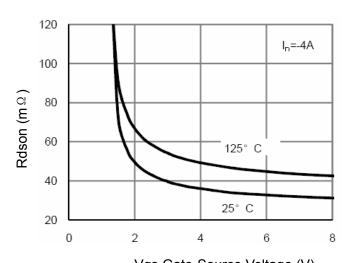
Figure 6 Drain-Source On-Resistance







**Figure 7 Transfer Characteristics** 



Vgs Gate-Source Voltage (V) Figure 9 Rdson vs Vgs

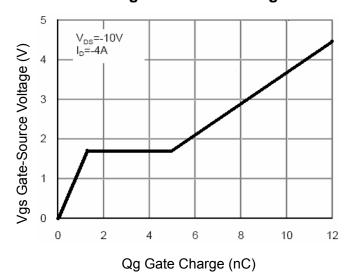


Figure 11 Gate Charge

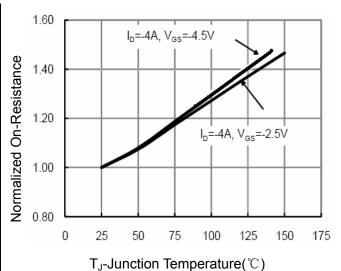


Figure 8 Drain-Source On-Resistance

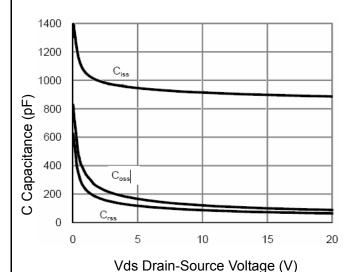
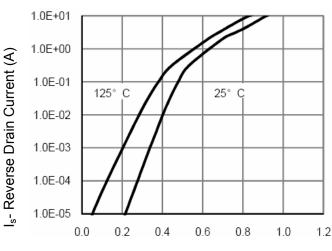


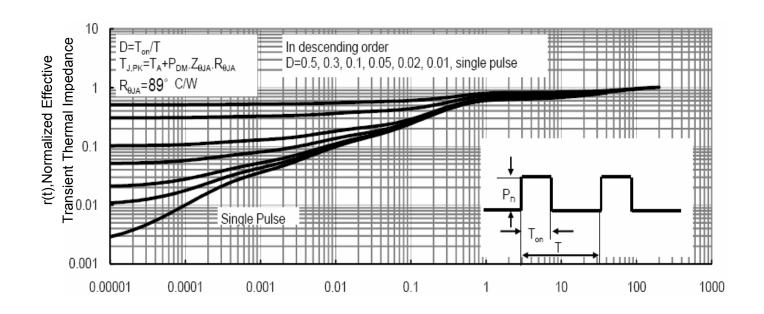
Figure 10 Capacitance vs Vds



Vsd Source-Drain Voltage (V)

Figure 12 Source- Drain Diode Forward

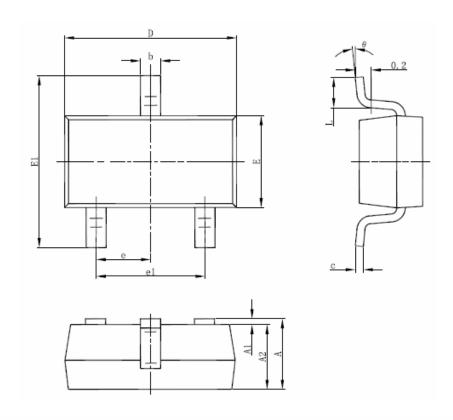




Square Wave Pluse Duration(sec)

**Figure 13 Normalized Maximum Transient Thermal Impedance** 

## **SOT-23-3L Package Information**



Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
e	0.950(BSC)		0.037(BSC)		
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

## **Notes**

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact



#### http://www.ncepower.com

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